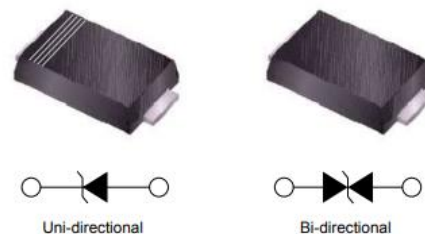


SMD Type 200 W

■ Features

1. Glass passivated chip
2. 200W peak pulse power capability at 10/1000 μ s waveform, repetition rate (duty cycle): 0.01%
3. Excellent clamping capability
4. Very fast response time
5. Low clamping voltage
6. Low leakage current
7. Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C
8. JESD22-A114-B ESD Voltage: HBM 15KV
9. JEDEC EIA/JESD22-C101F ESD Voltage: CDM 500V
10. JEDEC EIA/JESD22-A115 ESD Voltage: MM 400V
11. ESD-immunity acc. IEC 61000-4-2 \pm 30kV(contact), \pm 30kV(air)
12. Halogen free and RoHS compliant



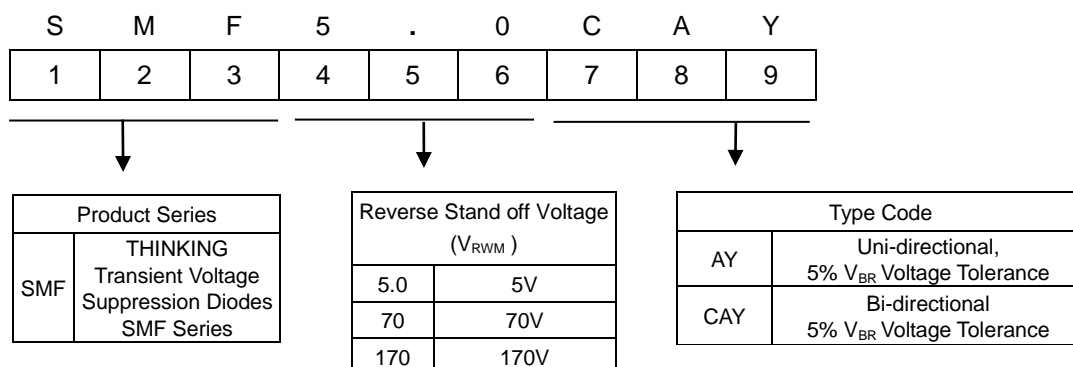
■ Recommended Applications

1. Computers
2. Telecom system
3. Industrial equipment
4. Consumer electronic applications
5. Other VCC bus and I/O interfaces

■ Mechanical Data

1. Case: Molded plastic, SOD-123FL
2. Epoxy: UL 94V-0 rate flame retardant
3. Terminals: Solderable per MIL-STD-750, method 2026
4. Polarity: Color band denotes cathode end
5. Mounting Position: Any

■ Part Number Code

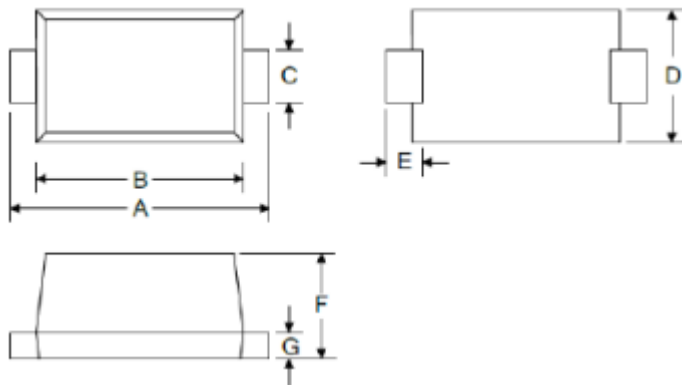


TVS Diode: SMF Series

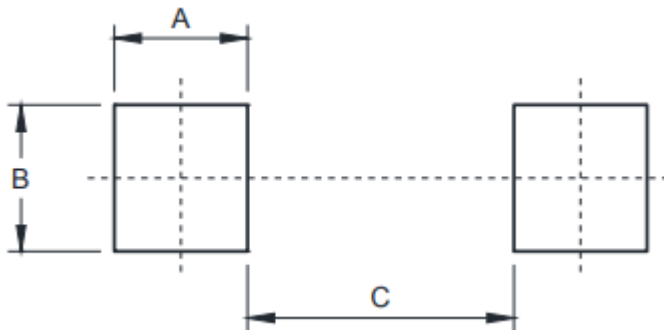
SMD Type 200 W



Structures and Dimensions



Symbol	Dimensions in millimeters	
	Min	Max
A	3.50	3.90
B	2.60	3.00
C	0.90	1.10
D	1.60	2.00
E	0.80 Typ.	
F	0.90	1.40
G	0.12	0.22



Symbol	Unit (mm)	Unit (inch)
A	1.0	0.039
B	1.1	0.043
C	2.0	0.079

Maximum Rating ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak power dissipation with a 10/1000 μs waveform (Note 1,2)	P_{PPM}	200	W
Peak pulse current with 10/1000 μs waveform (Note 1)	I_{PPM}	See next table	A
Peak forward surge current, 8.3 ms single half sine-wave (Note 3)	I_{FSM}	20	A
Power dissipation on infinite heatsink at $T_L=50^\circ\text{C}$	P_D	1	W
Typical thermal resistance junction to ambient	$R_{\theta JA}$	220	$^\circ\text{C/W}$
Typical thermal resistance junction to lead	$R_{\theta JL}$	100	$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Note:

1. Non-repetitive current pulse, per Fig. 3 and derated above $T_A=25^\circ\text{C}$ per Fig. 2.
2. Mounted on 5.0 x 5.0mm copper pad to each terminal.
3. Measured on 8.3ms single half sine wave or equivalent square wave for unidirectional device only, duty cycle=4 per minute maximum.

■ Electrical Characteristics (T_A=25°C unless otherwise noted)

Part No. (Uni)	Part No. (Bi)	Reverse Stand off Voltage V _{RWM} (V)	Breakage Voltage V _{BR} @ I _T		Test Current I _T (mA)	Maximum Clamping Voltage V _C @ I _{pp} V _C (V)	Maximum Peak Pulse Current I _{pp} (A)	Maximum Reverse Leakage I _R @ V _{RWM} I _R (μA)	Marking Code	
			Min(V)	Max(V)					Uni	Bi
SMF5.0AY	SMF5.0CAY	5	6.4	7.07	10	9.2	21.74	400	AE	WE
SMF6.0AY	SMF6.0CAY	6	6.67	7.37	10	10.3	19.42	400	AG	WG
SMF6.5AY	SMF6.5CAY	6.5	7.22	7.98	10	11.2	17.86	250	AK	WK
SMF7.0AY	SMF7.0CAY	7	7.78	8.6	10	12	16.67	100	AM	WM
SMF7.5AY	SMF7.5CAY	7.5	8.33	9.21	1	12.9	15.51	50	AP	WP
SMF8.0AY	SMF8.0CAY	8	8.89	9.83	1	13.6	14.71	25	AR	WR
SMF8.5AY	SMF8.5CAY	8.5	9.44	10.4	1	14.4	13.89	10	AT	WT
SMF9.0AY	SMF9.0CAY	9	10	11.1	1	15.4	12.99	5	AV	WV
SMF10AY	SMF10CAY	10	11.1	12.3	1	17	11.77	1	AX	WX
SMF11AY	SMF11CAY	11	12.2	13.5	1	18.2	10.99	1	AZ	WZ
SMF12AY	SMF12CAY	12	13.3	14.7	1	19.9	10.05	1	BE	XE
SMF13AY	SMF13CAY	13	14.4	15.9	1	21.5	9.3	1	BG	XG
SMF14AY	SMF14CAY	14	15.6	17.2	1	23.2	8.62	1	BK	XK
SMF15AY	SMF15CAY	15	16.7	18.5	1	24.4	8.2	1	BM	XM
SMF16AY	SMF16CAY	16	17.8	19.7	1	26	7.69	1	BP	XP
SMF17AY	SMF17CAY	17	18.9	20.9	1	27.6	7.25	1	BR	XR
SMF18AY	SMF18CAY	18	20	22.1	1	29.2	6.85	1	BT	XT
SMF20AY	SMF20CAY	20	22.2	24.5	1	32.4	6.18	1	BV	XV
SMF22AY	SMF22CAY	22	24.4	26.9	1	35.5	5.64	1	BX	XX
SMF24AY	SMF24CAY	24	26.7	29.5	1	38.9	5.14	1	BZ	XZ
SMF26AY	SMF26CAY	26	28.9	31.9	1	42.1	4.75	1	CE	YE
SMF28AY	SMF28CAY	28	31.1	34.4	1	45.4	4.41	1	CG	YG
SMF30AY	SMF30CAY	30	33.3	36.8	1	48.4	4.13	1	CK	YK
SMF33AY	SMF33CAY	33	36.7	40.6	1	53.3	3.75	1	CM	YM
SMF36AY	SMF36CAY	36	40	44.2	1	58.1	3.44	1	CP	YP
SMF40AY	SMF40CAY	40	44.4	49.1	1	64.5	3.1	1	CR	YR
SMF43AY	SMF43CAY	43	47.8	52.8	1	69.4	2.88	1	CT	YT
SMF45AY	SMF45CAY	45	50	55.3	1	72.7	2.75	1	CV	YV
SMF48AY	SMF48CAY	48	53.3	58.9	1	77.4	2.59	1	CX	YX

■ Electrical Characteristics (T_A=25°C unless otherwise noted)

Part No. (Uni)	Part No. (Bi)	Reverse Stand off Voltage	Breakage Voltage V _{BR} @ I _T		Test Current I _T (mA)	Maximum Clamping Voltage V _C @ I _{pp}	Maximum Peak Pulse Current I _{pp} (A)	Maximum Reverse Leakage I _R @ V _{RWM}	Marking Code	
			V _{RWM} (V)	Min(V)					Max(V)	Uni
SMF51AY	SMF51CAY	51	56.7	62.7	1	82.4	2.43	1	CZ	YZ
SMF54AY	SMF54CAY	54	60	66.3	1	87.1	2.3	1	RE	ZE
SMF58AY	SMF58CAY	58	64.4	71.2	1	93.6	2.14	1	RG	ZG
SMF60AY	SMF60CAY	60	66.7	73.7	1	96.8	2.07	1	RK	ZK
SMF64AY	SMF64CAY	64	71.1	78.6	1	103	1.94	1	RM	ZM
SMF70AY	SMF70CAY	70	77.8	86	1	113	1.77	1	RP	ZP
SMF75AY	SMF75CAY	75	83.3	92.1	1	121	1.66	1	RR	ZR
SMF78AY	SMF78CAY	78	86.7	95.8	1	126	1.59	1	RT	ZT
SMF85AY	SMF85CAY	85	94.4	104	1	137	1.46	1	RV	ZV
SMF90AY	SMF90CAY	90	100	111	1	146	1.37	1	RX	ZX
SMF100AY	SMF100CAY	100	111	123	1	162	1.24	1	RZ	ZZ
SMF110AY	SMF110CAY	110	122	135	1	177	1.13	1	SE	VE
SMF120AY	SMF120CAY	120	133	147	1	193	1.04	1	SG	VG
SMF130AY	SMF130CAY	130	144	159	1	209	0.96	1	SK	VK
SMF150AY	SMF150CAY	150	167	185	1	243	0.83	1	SM	VM
SMF160AY	SMF160CAY	160	178	197	1	259	0.77	1	SP	VP
SMF170AY	SMF170CAY	170	189	209	1	275	0.73	1	SR	VR
SMF180AY	SMF180CAY	180	201	222	1	292	0.68	1	ST	VT
SMF200AY	SMF200CAY	200	224	247	1	324	0.62	1	SV	VV

■ Typical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Fig.1 - Peak Pulse Power Rating Curve

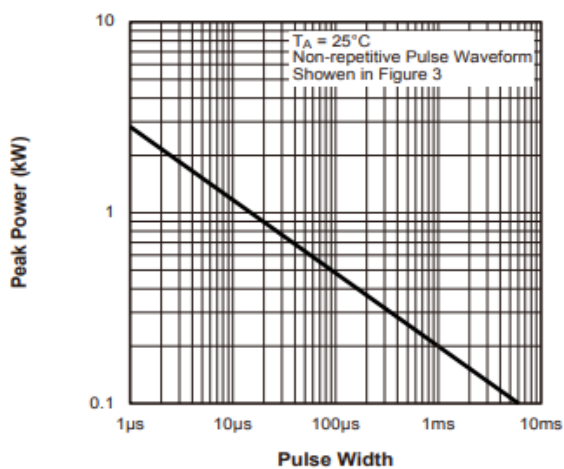


Fig.2 - Pulse Derating Curve

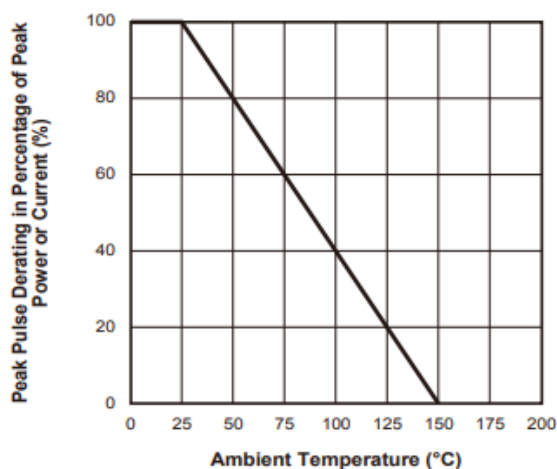


Fig.3 - Pulse Waveform

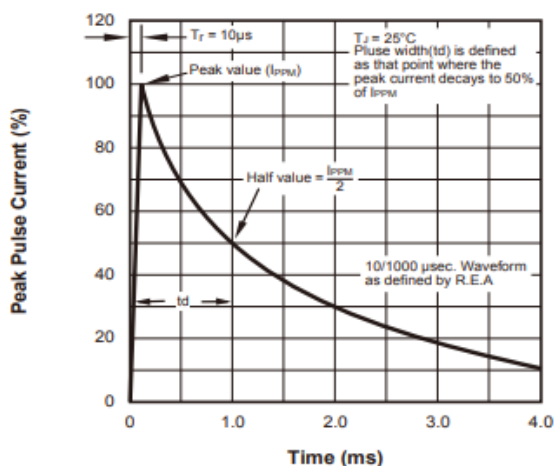
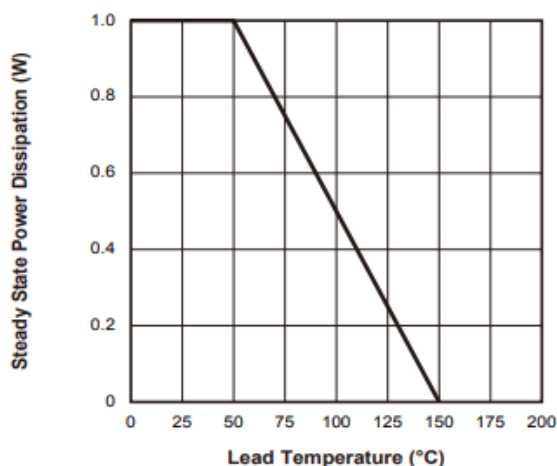
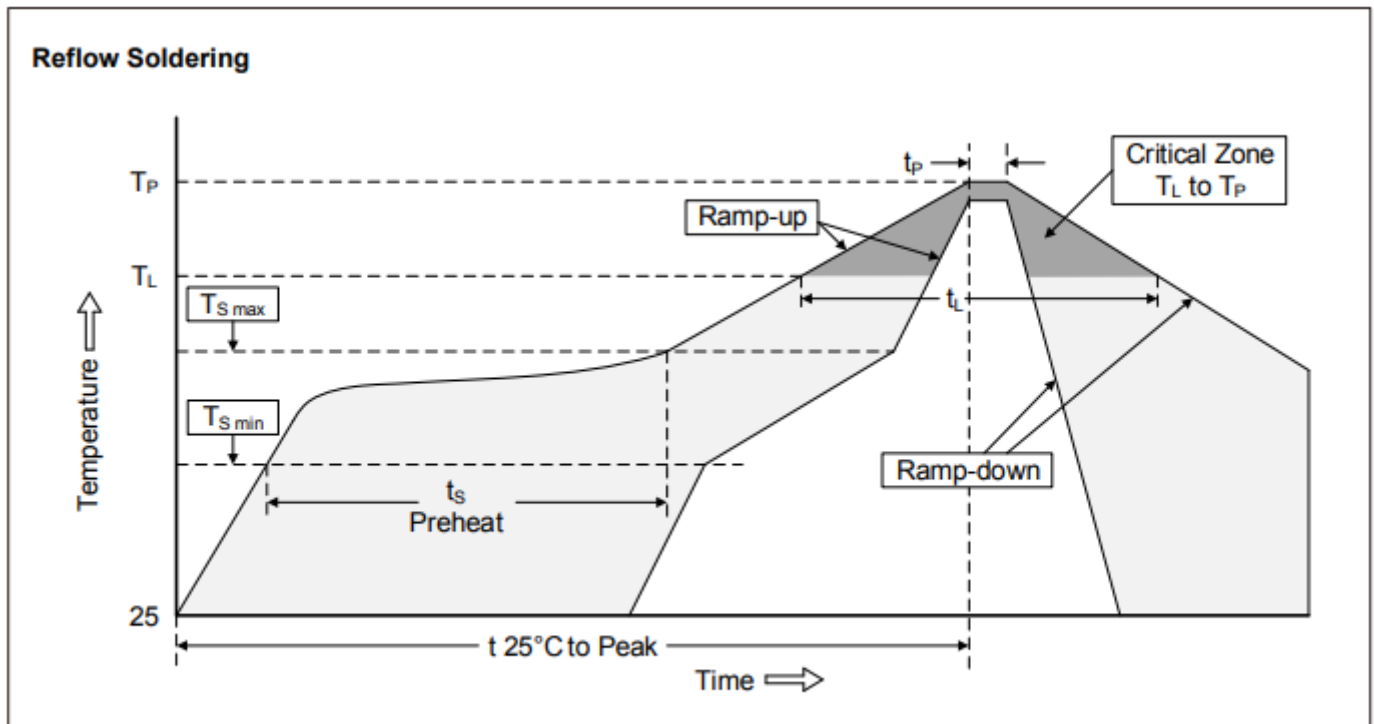


Fig.4 - Steady State Power Derating Curve



SMD Type 200 W

■ Soldering Recommendation

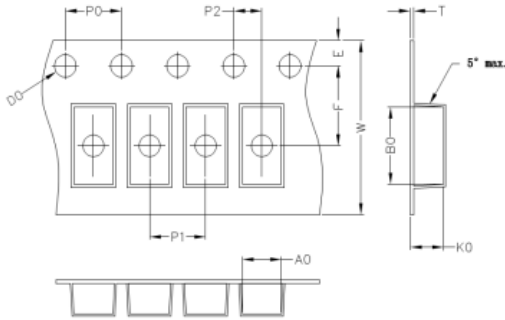


Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	3°C/second max.
Preheat	
-Temperature Min ($T_{S\ min}$)	150°C
-Temperature Max ($T_{S\ max}$)	200°C
-Time (min to max) (t_s)	60-180 seconds
$T_{S\ max}$ to T_L	
-Ramp-up Rate	3°C/second max.
Time maintained above:	
-Temperature (T_L)	217°C
-Time (t_L)	60-150 seconds
Peak Temperature (T_P)	260°C
Time within 5°C of actual Peak Temperature (t_p)	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

SMD Type 200 W

■ Packaging



Symbol	A0	B0	K0	D0	E	F
Unit (mm)	2.15±0.1	3.95±0.1	13.5±0.1	1.5±0.1	1.75±0.1	3.5±0.1
Symbol	P0	P1	P2	T	W	
Unit (mm)	4.0±0.1	4.0±0.1	2.0±0.1	0.25±0.1	8.0±0.3	

■ Quantity

Series Type	Packaging option	Base quantity	Packaging specification
SMF	Tape and reel	3000pcs / reel	EIA STD RS-481

■ Warehouse Storage Conditions of Product

- Storage Condition:
 1. Storage Temperature: -10°C ~ +40°C
 2. Relative Humidity: $\leq 75\%RH$
 3. Keep away from corrosive atmosphere and sunlight.
- Period of Storage: 1 year.